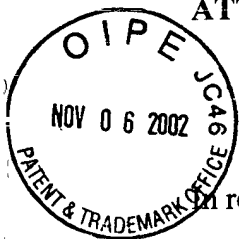


2811

ATTORNEY DOCKET NO.: S.A. LYTLE 18

PATENT



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Stephen A. Lytle

Serial No.: 09/667,046

Filed: September 21, 2000

For: DUAL DAMASCENE PROCESS WITH NO PASSING METAL FEATURES

Grp./A.U.: 2811

Examiner: Hung K. Vu

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Honorable Commissioner of Patents
Washington, D.C. 20231

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail in an envelope addressed to: Commissioner of Patents and Trademarks, Washington, D.C. 20231, on 10/31/2002 (Date)
EDITH SHEIK
(Printed or typed name of person signing the certificate)
Edith Sheik
(Signature of the person signing the certificate)

Sir:

AMENDMENT UNDER 37 C.F.R. § 1.111

In response to the Examiner's Action mailed July 31, 2002, please amend the above-identified application as follows:

IN THE CLAIMS:

(1) Please amend Claim 21 as follows:

21. (Three Times Amended) A semiconductor device, comprising:
a first interconnect metal located on or in a first interlevel dielectric layer;

CY